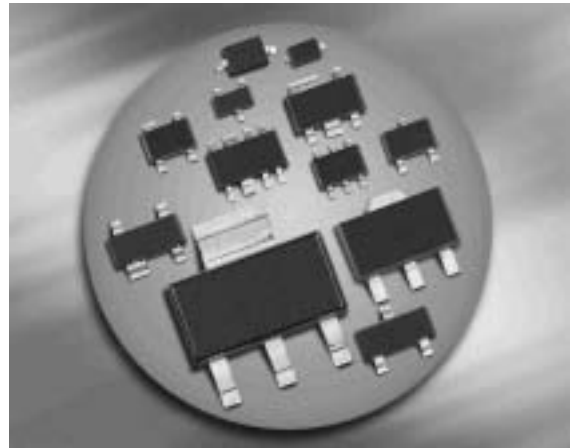
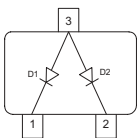


Silicon Switching Diode

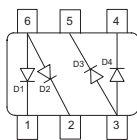
- For high-speed switching applications
- Common anode configuration



BAW56
BAW56T
BAW56W



BAW56S
BAW56U



Type	Package	Configuration	Marking
BAW56	SOT23	common anode	A1s
BAW56S	SOT363	double common anode	A1s
BAW56T	SC75	common anode	A1s
BAW56U	SC74	double common anode	A1s
BAW56W	SOT323	common anode	A1s

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	80	V
Peak reverse voltage	V_{RM}	85	
Forward current	I_F	200	mA
Surge forward current, $t = 1 \mu\text{s}$	I_{FS}	4.5	A
Total power dissipation	P_{tot}		mW
BAW56, $T_S \leq 31^\circ\text{C}$		330	
BAW56S, $T_S \leq 85^\circ\text{C}$		250	
BAW56T, $T_S \leq 104^\circ\text{C}$		250	
BAW56U, $T_S \leq 90^\circ\text{C}$		250	
BAW56W, $T_S \leq 103^\circ\text{C}$		250	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

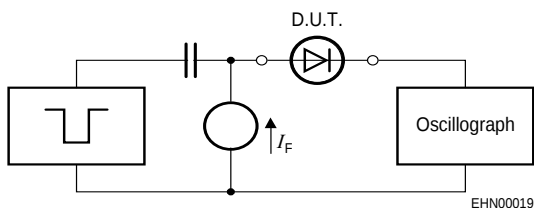
Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BAW56		360	
BAW56S		260	
BAW56T		185	
BAW56U		240	
BAW56W		190	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)} = 100 \mu A$	$V_{(BR)}$	85	-	-	V
Reverse current $V_R = 70 V$ $V_R = 25 V, T_A = 150\text{ }^{\circ}C$ $V_R = 70 V, T_A = 150\text{ }^{\circ}C$	I_R	- - -	- - -	0.15 30 50	μA
Forward voltage $I_F = 1 mA$ $I_F = 10 mA$ $I_F = 50 mA$ $I_F = 100 mA$ $I_F = 150 mA$	V_F	- - - - -	- - - - -	715 855 1000 1200 1250	mV
AC Characteristics					
Diode capacitance $V_R = 0 V, f = 1 MHz$	C_T	-	-	2	pF
Reverse recovery time $I_F = 10 mA, I_R = 10 mA$, measured at $I_R = 1mA$, $R_L = 100 \Omega$	t_{rr}	-	-	4	ns

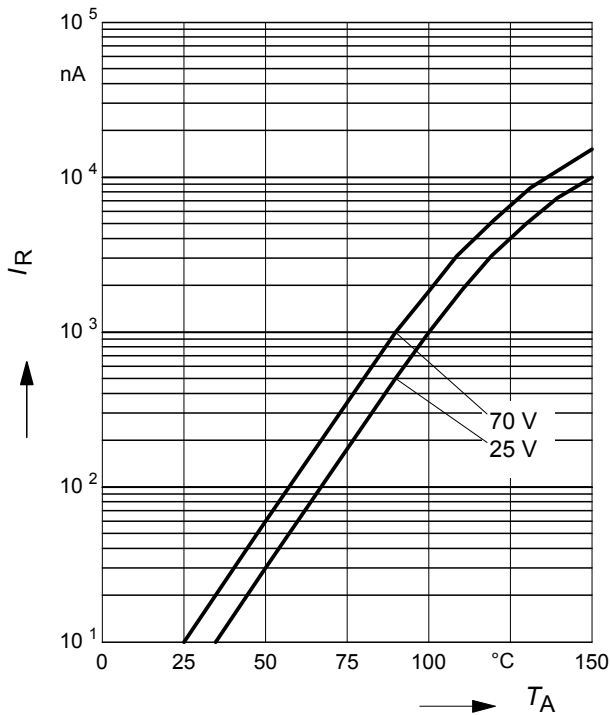
Test circuit for reverse recovery time


Pulse generator: $t_p = 100\text{ns}$, $D = 0.05$, $t_r = 0.6\text{ns}$,
 $R_i = 50\Omega$

Oscilloscope: $R = 50\Omega$, $t_r = 0.35\text{ns}$, $C \leq 1\text{pF}$

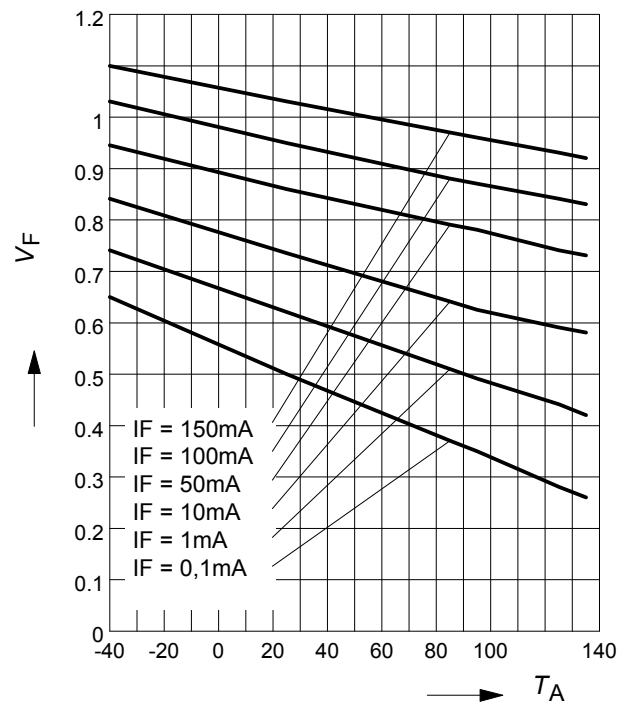
Reverse current $I_R = f(T_A)$

$V_R = \text{Parameter}$



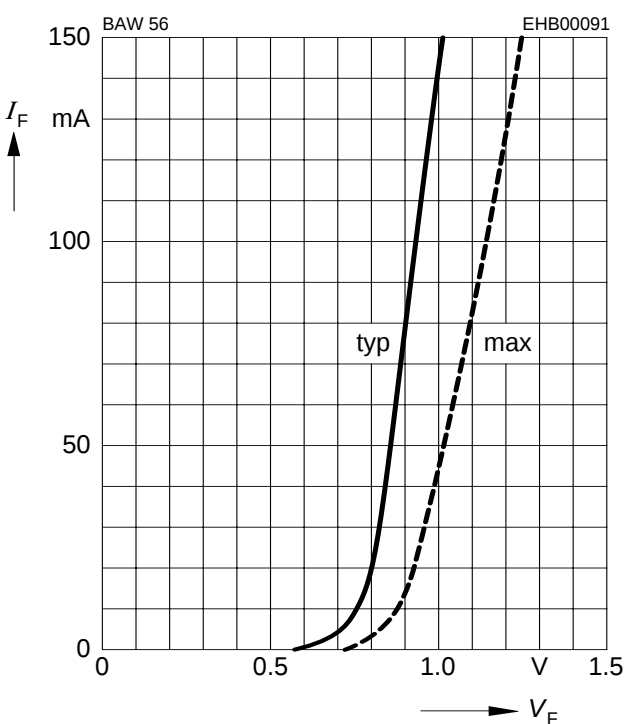
Forward Voltage $V_F = f(T_A)$

$I_F = \text{Parameter}$



Forward current $I_F = f(V_F)$

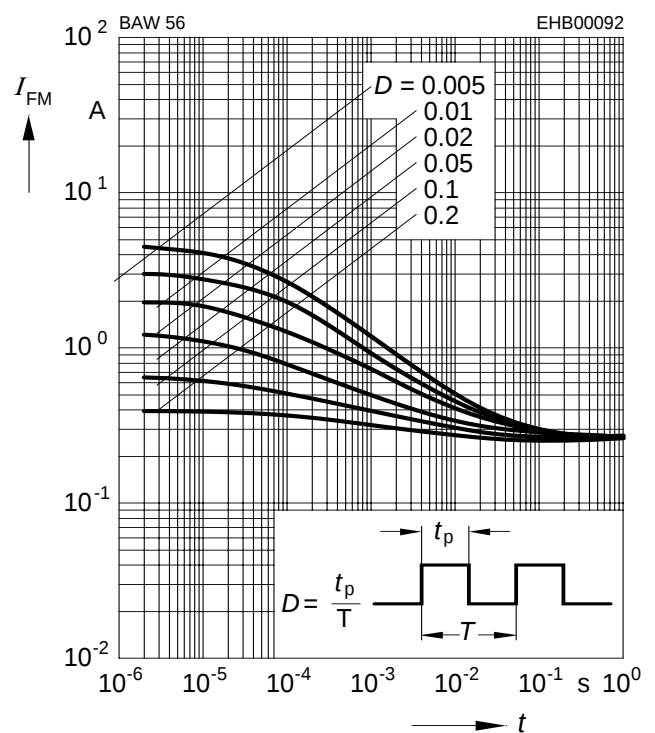
$T_A = 25^\circ\text{C}$



Peak forward current $I_{FM} = f(t_p)$

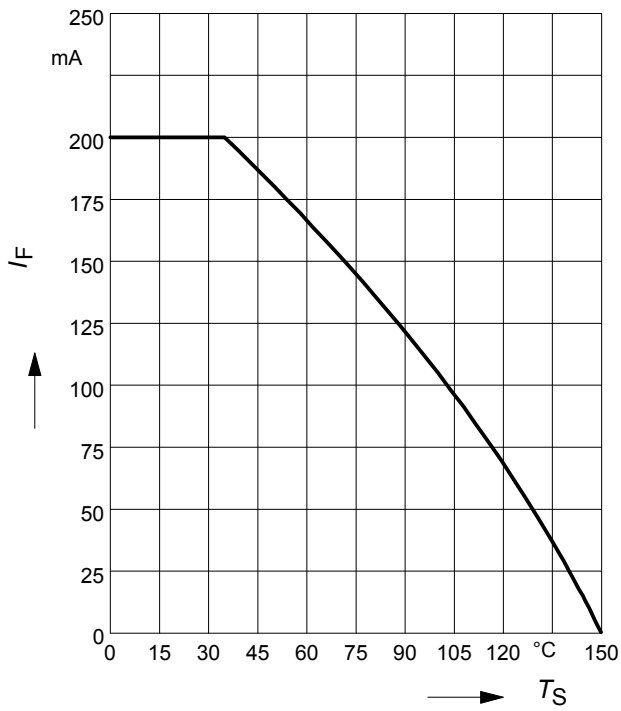
$T_A = 25^\circ\text{C}$

BAW56



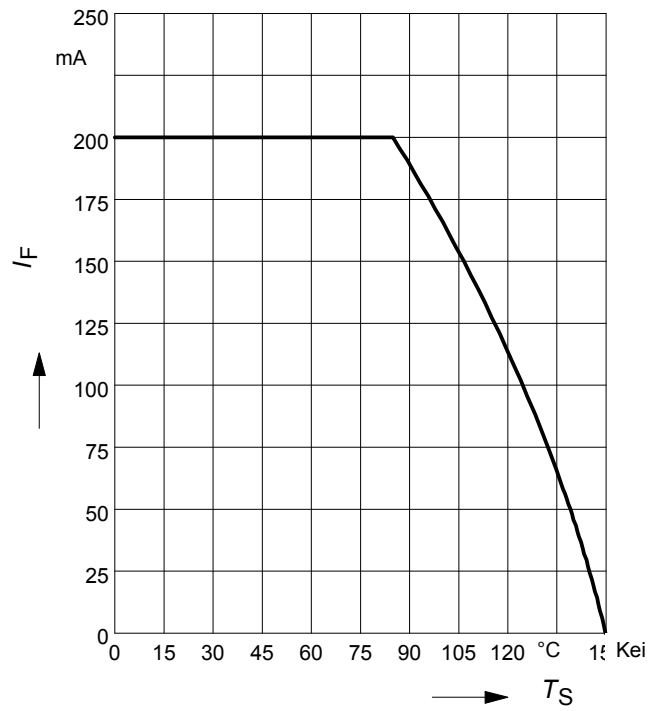
Forward current $I_F = f(T_S)$

BAW56



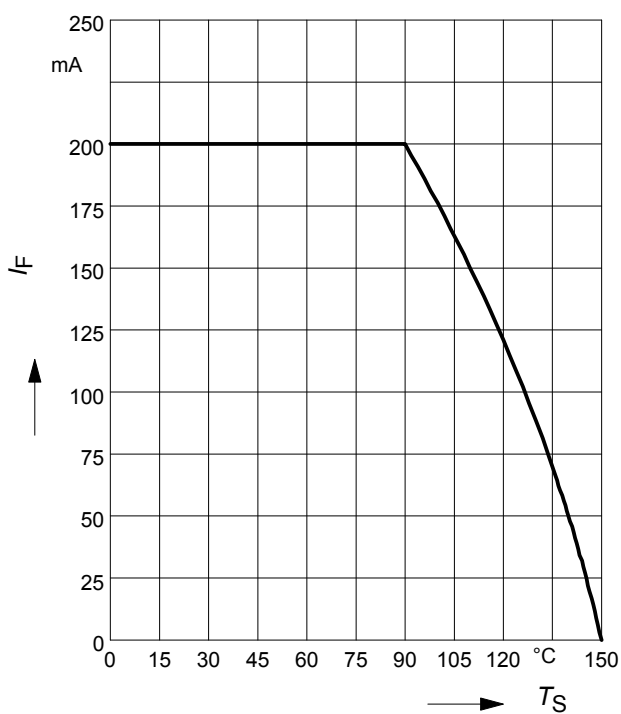
Forward current $I_F = f(T_S)$

BAW56S



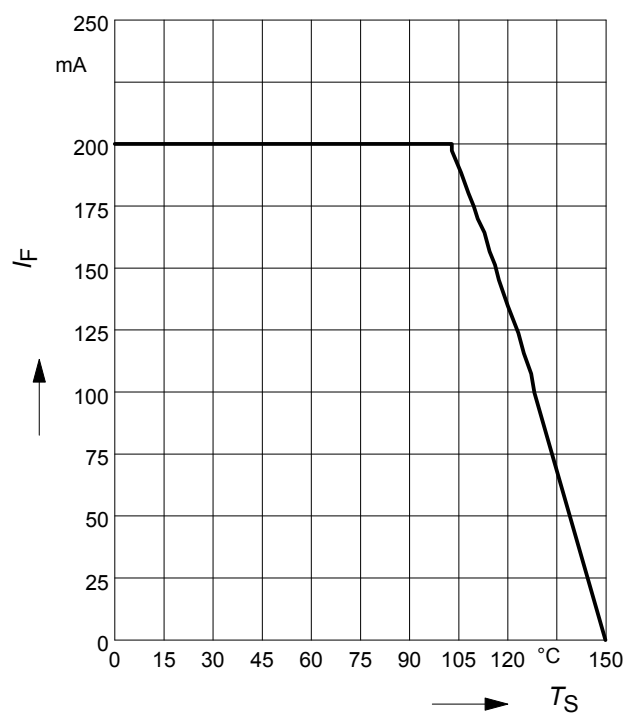
Forward current $I_F = f(T_S)$

BAW56U



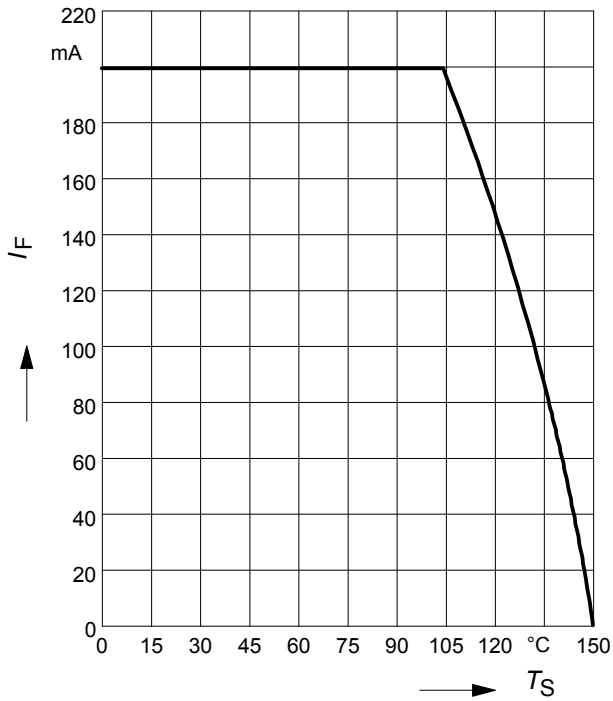
Forward current $I_F = f(T_S)$

BAW56W



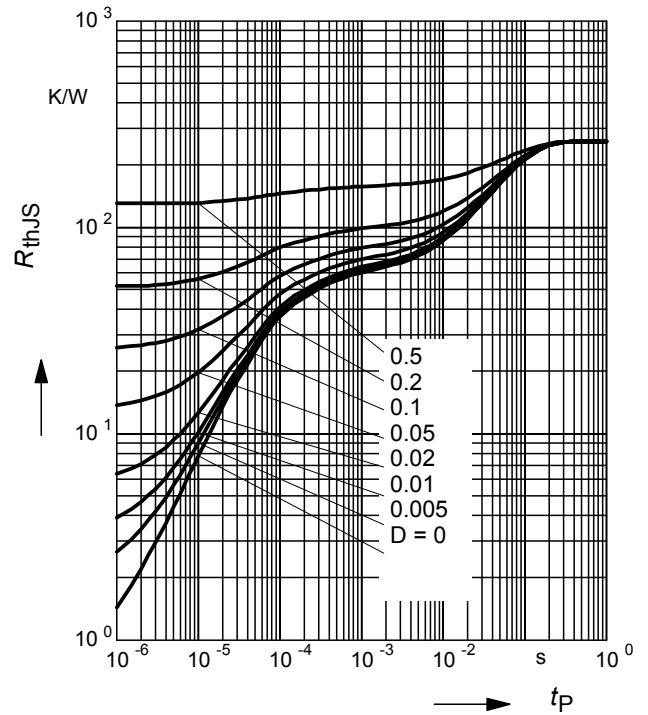
Forward current $I_F = f(T_S)$

BAW56T



Permissible Puls Load $R_{thJS} = f(t_p)$

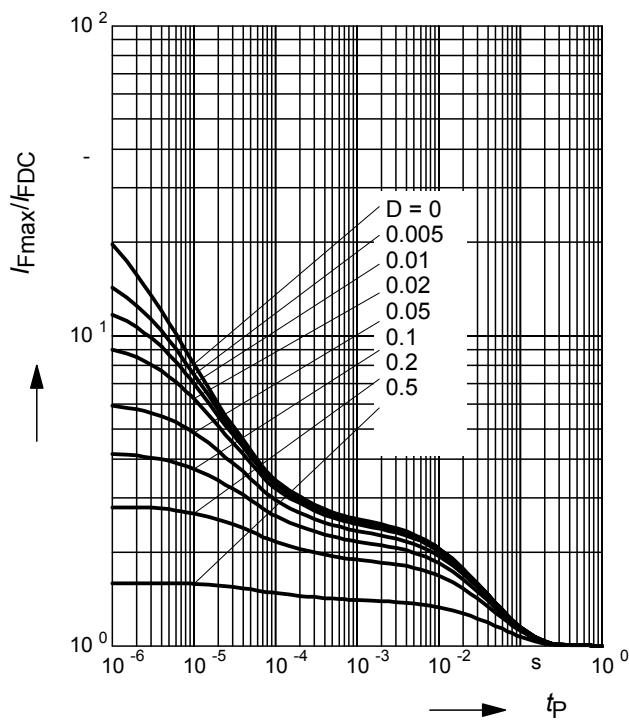
BAW56S



Permissible Pulse Load

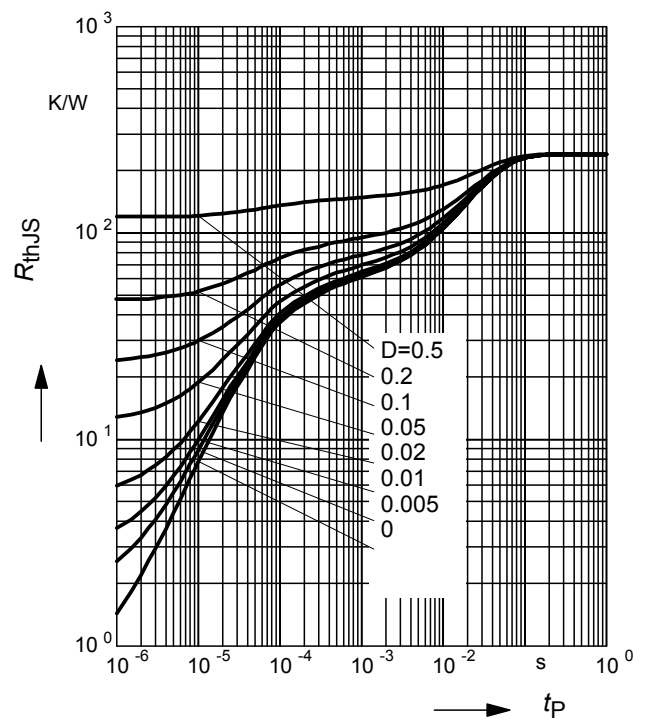
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAW56S



Permissible Puls Load $R_{thJS} = f(t_p)$

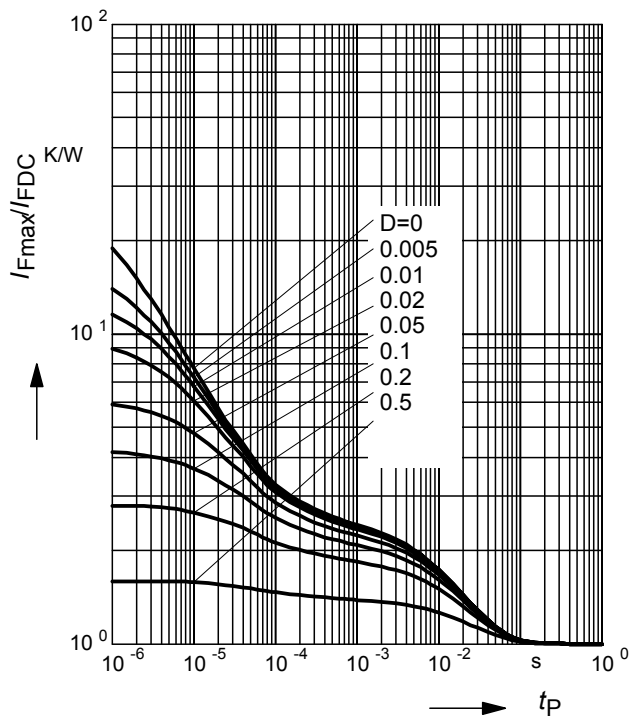
BAW56U



Permissible Pulse Load

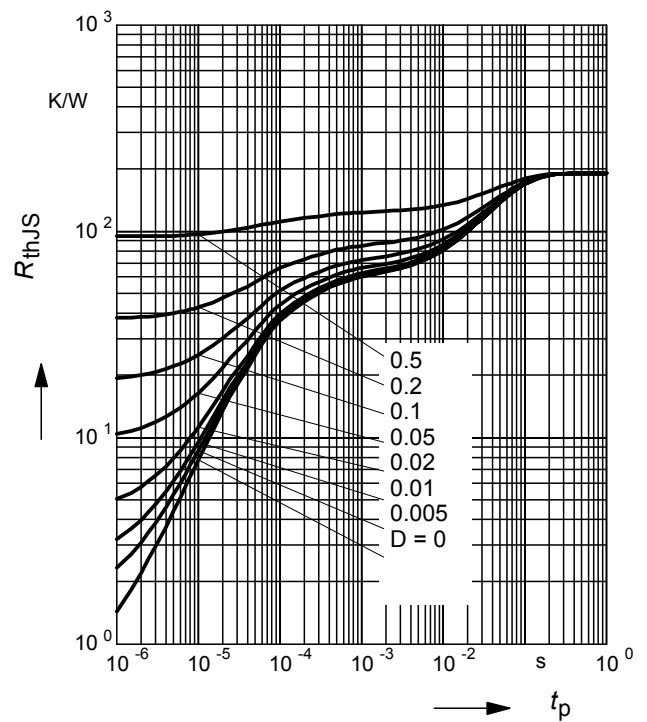
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAW56U



Permissible Puls Load $R_{thJS} = f(t_p)$

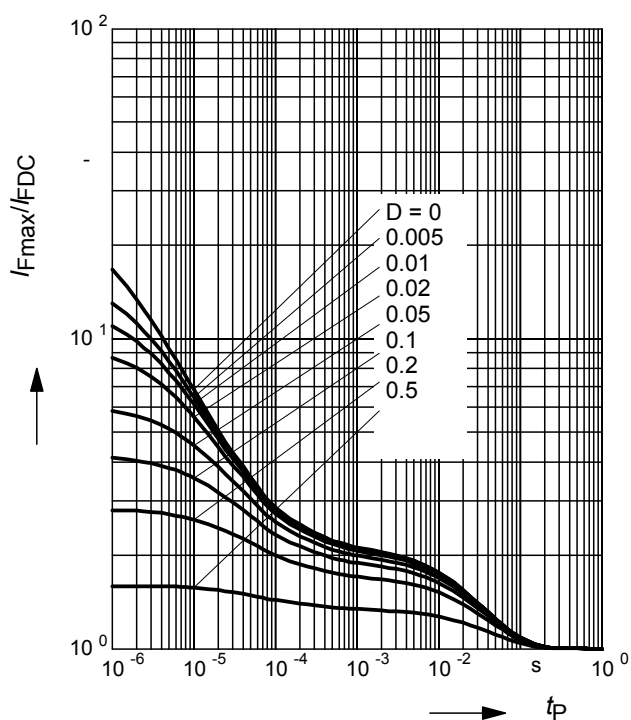
BAW56W



Permissible Pulse Load

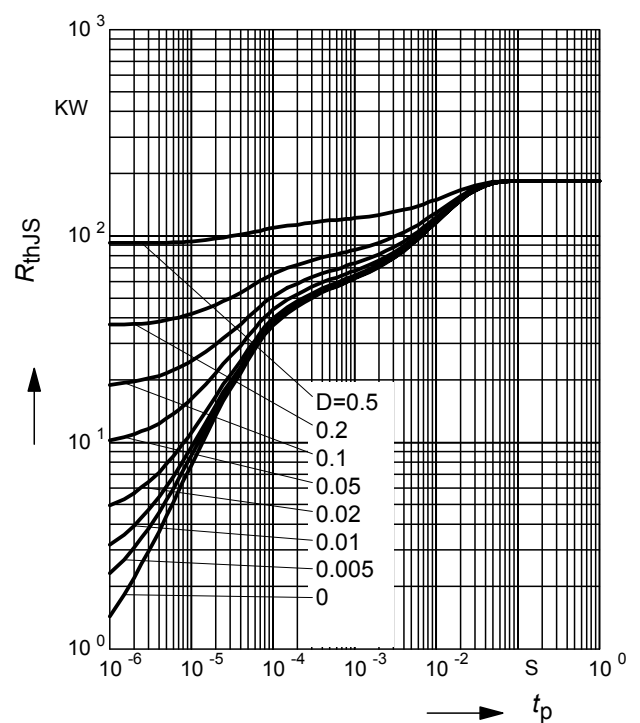
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAW56W



Permissible Puls Load $R_{thJS} = f(t_p)$

BAW56T



Permissible Pulse Load

$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAW56T

